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Force between a magnetic tip and an inhomogeneous superconductor at zero field *

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The force exerted by a semi-infinite inhomogeneous superconductor with a planar interface to vacuum on a magnetic tip is studied theoretically in the absence of external magnetic fields. It is shown that the force has a contribution from inhomogeneities due to material defects with unique characteristics. Defects are taken into account in the London limit by allowing the mass parameter to vary spatially. The contribution from defects to the force is calculated analytically to first order in the deviation of the mass parameter from its constant value for the homogeneous superconductor, assuming that the tip is a point dipole perpendicular to the interface, and that it does not spontaneously create vortex matter. Random point defects and linear localized defects are considered phenomenologically. For each defect type the force dependence on the dipole position coordinates is obtained, and the force magnitudes are estimated numerically. The predictions for the dependence of the linear defect force on the dipole lateral position are found to agree qualitatively with experiment.

A magnet and a superconductor placed in the vicinity of each other interact through a force that results from the changes in the superconducting state induced by the magnet. Since inhomogeneities in the superconductor due to material defects modify the magnet-superconductor interaction, the force must contain contributions from defects. This contribution must be present in the force on a magnetic tip measured by the technique of magnetic force microscopy (MFM) [1] applied at zero external field, and can, in principle, be measured if its magnitude is larger than the MFM resolution, about $1\,pN$.

For planar superconductor-vacuum interfaces, as assumed here, translational symmetry considerations alone suggest that there is a contribution from defects to the force on the tip with unique characteristics. For defect-free materials, the tip-superconductor interaction energy is invariant under translations parallel to the interface, and depends only on the tip-superconductor distance. This implies that the force on the tip, equal to the gradient of the interaction energy, is perpendicular to the interface and independent of the tip lateral position coordinates. This is no longer true if the superconductor has defects, because translational invariance is broken. The tip-superconductor interaction energy now depends also on the tip lateral position, and so does the force, which is no longer perpendicular to the interface. Thus, the force on the tip has a contribution from defects with components parallel and perpendicular to the interface, both dependent on the tip lateral position as well as on the tip-superconductor distance. This contribution can, in principle, be singled out in MFM measurements since it is responsible for the lateral force component and for the dependence of both force components on the tip lateral tip position. The objective of this paper is to study the properties of the contribution from defects to the force and to estimate its magnitude using a simple model.

The general framework for the description of inhomogeneous superconductors is the Ginzburg-Landau (G-L) model with spatially varying coefficients of the G-L free-energy expansion [2]. Here the G-L model is used in the London limit, in which case only the mass parameter of the G-L expansion appears. The effect of the tip magnetic field on the superconductor is to induce a

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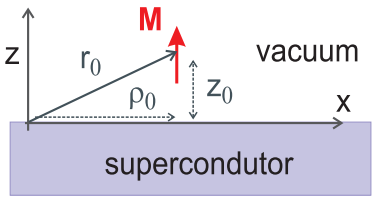

Figure 1. Schematic view of semi-infinite superconductor and point dipole $\mathbf{M} = M_z\hat{\mathbf{z}}$, at $\mathbf{r}_0 = (\boldsymbol{\rho}_0, z_0)$.

screening current and create vortex matter, when the tip is close enough to the interface. Here the defect contribution to the force is calculated assuming that the tip does not create vortex matter. This is the situation of greatest interest because, as shown here, the defect contribution results solely from to the spatial dependence of the mass parameter.

The model considers a semi-infinite isotropic superconductor, separated from the vacuum by a planar interface parallel to the $x-y$ plane, occupying the region $-\infty \leq z \leq 0$. The magnetic tip is approximated by a point dipole perpendicular to the interface, $\mathbf{M} = M_z\hat{\mathbf{z}}$, placed at $\mathbf{r}_0 = (x_0, y_0, z_0) \equiv (\boldsymbol{\rho}_0, z_0 > 0)$ (Fig. 1). The free-energy in the London limit, assuming that the superconductor is vortex matter free, is given by [2]

$$G = \int d^2\rho \int_{-\infty}^{0} dz \frac{|\,\mathbf{A}\,|^2}{8\pi\lambda^2} + \int d^3r \frac{|\,\boldsymbol{\nabla}\times\mathbf{A}\,|^2}{8\pi} \quad .(1)$$

where $\mathbf{r} \equiv (\boldsymbol{\rho}, z)$, $\mathbf{A}(\mathbf{r})$ is the vector potential, and λ is the penetration depth, related to the G-L mass parameter, m, by $\lambda^2 = mc^2/(4\pi n_s e^{*2})$, where $e^* = 2e$, and n_s is the density of Cooper pairs. For homogeneous superconductors the mass parameter is a constant, m_0, and so is the penetration depth, λ_0. Inhomogeneities are described by m dependent on the spatial coordinates, $m(\boldsymbol{\rho}, z) = m_0 + \delta m(\boldsymbol{\rho}, z)$. Here it is assumed that $\delta m/m_0 \ll 1$. The free-energy to first order in $\delta m/m_0$ is written as $G^{(1)}(\mathbf{r}_0) = G^{(0)}(z_0) + \delta G(\mathbf{r}_0)$. The first term, $G^{(0)}$, is the homogeneous superconductor free-energy, given by Eq. (1) with $m = m_0$, and $\mathbf{A}$ equal to the equilibrium vector potential in the absence of defects, denoted $\mathbf{A}_0(\mathbf{r})$. It depends only on z_0 because of translational invariance parallel to the interface. The second term is the first order correction, given by

$$\delta G(\mathbf{r}_0) = -\int d^2\rho \int_{-\infty}^{0} dz \frac{|\,\mathbf{A}_0(\boldsymbol{\rho}, z)\,|^2}{8\pi\lambda_0^2} \frac{\delta m(\boldsymbol{\rho}, z)}{m_0} \quad .(2)$$

The correction to first order in $\delta m/m_0$ to the free energy, Eq. (2), is just the change in the kinetic energy of the homogeneous superconductor caused by the inhomogeneity, since the screening current is given by $\mathbf{j}_{sc} = -(n_s e^{*2}/m_0 c)\mathbf{A}_0$. The force on the dipole is $\mathbf{F}^{(1)}(\mathbf{r}_0) = F^{(0)}(z_0)\hat{\mathbf{z}} + \delta\mathbf{F}(\mathbf{r}_0)$ where the first term is the homogeneous superconductor contribution with $F^{(0)}(z_0) = -dG^{(0)}(z_0)/dz_0$ and $\delta\mathbf{F}(\mathbf{r}_0) = -\boldsymbol{\nabla}_0\delta G(\mathbf{r}_0)$ is the contribution from defects.

The homogeneous superconductor free-energy is $G^{(0)}(z_0) = -M_z\, b'_z(z_0)/2$, where b'_z is the z-component of the magnetic field of the dipole screening supercurrent at the position of the dipole [3]. The calculations carried out here use the analytic expressions for b'_z, and $\mathbf{A}_0$ obtained in Ref.[3]. The force $F^{(0)}(z_0)$ is repulsive ($F^{(0)}(z_0) > 0$) and increases as z_0 decreases, typically as shown in Fig. 2. For the dipole at ($\boldsymbol{\rho}_0 = 0, z_0 > 0$), $\mathbf{A}_0$ is given by $\mathbf{A}_0(\boldsymbol{\rho}, z; z_0) = A_\theta(\rho, z; z_0)\,\hat{\boldsymbol{\theta}}$, and $\hat{\boldsymbol{\theta}}$ is the unit vector in the direction of the polar angle. For the dipole located at $\boldsymbol{\rho}_0 \neq 0$, the vector potential is $\mathbf{A}_0(\boldsymbol{\rho}-\boldsymbol{\rho}_0, z; z_0)$, because of translational invariance parallel to the interface. A typical dependence of A_θ on ρ at constant z is shown in Fig. 2. For other values of z_0 and z, A_θ decreases smoothly as $|\,z\,|$ increases, vanishing for $|\,z\,| \gg \lambda_0$, and also decreases with increasing z_0.

Next, the contribution from defects to the force is calculated for random point defects and linear localized defects, assuming in each case that the spatial dependence of $\delta m(\boldsymbol{\rho}, z)$ is know.

Random Point Defects. In this case $\delta m(\mathbf{r})$ is a random function with zero average satisfying $< \delta m(\mathbf{r})\delta m(\mathbf{r}') >= \gamma_m\,\delta(\mathbf{r}-\mathbf{r}')$, where $<>$ denotes average over the randomness [2]. According to Eq. (2), the force is a random function of the dipole lateral position, $\boldsymbol{\rho}_0$, with zero average and

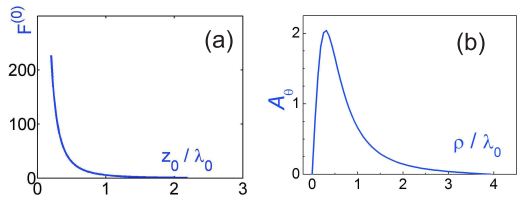

Figure 2. a) Dependence of $F^{(0)}(z_0)$ on z_0 ($F^{(0)}$ in units of $\epsilon_0 = (\phi_0/4\pi\lambda_0)^2$) for $M_z/\phi_0\lambda_0 = 1.0$. b) Dependence of $A_\theta(\rho, z; z_0)$ on ρ, for $\rho_0 = 0$, $z = -\lambda_0/8$, $z_0 = 0.3\lambda_0$, and $M_z/\phi_0\lambda_0 = 1.0$ (A_θ in units of ϕ_0/λ_0).

root mean square (RMS) fluctuation given by

$$<\mid \delta F_\alpha \mid^2>^{1/2} = 2\pi\epsilon_0(\frac{\gamma_m}{m_0^2\lambda_0^3})^{1/2}(\frac{M_z}{\phi_0\lambda_0})^2 R_\alpha(z_0)\ , \quad (3)$$

where α labels the force components (lateral: $\alpha = \rho$, perpendicular: $\alpha = z$), $\epsilon_0 = (\phi_0/4\pi\lambda_0)^2$, and R_α are dimensionless functions, independent of M_z, given by:
$R_\rho(z_0) = \lambda_0^{-2}\int d^2\rho \int_{-\infty}^0 dz \mid \boldsymbol{\nabla}_\rho a_0^2(\boldsymbol{\rho}, z; z_0) \mid^2$;
$R_z(z_0) = \lambda_0^{-2}\int d^2\rho \int_{-\infty}^0 dz \mid \partial a_0^2(\boldsymbol{\rho}, z; z_0)/\partial z_0 \mid^2$,
where $\mathbf{a}_0$, defined by $\mathbf{A}_0 \equiv (\phi_0/\lambda_0)(M_z/\phi_0\lambda_0)\mathbf{a}_0$, is dimensionless. The functions $R_\rho(z_0)$ and $R_z(z_0)$ decrease smoothly with increasing z_0, as shown in Fig. 3a. For a numerical estimate of $<\mid \delta F_\alpha \mid^2>^{1/2}$ the value of γ_m is taken from Ref.[2], obtained from collective vortex pinning theory at low temperatures, namely $\gamma_m/(m_0^2\xi^3) \sim 10^{-2}$, where ξ is the vortex core radius. Thus $\gamma_m/(m_0^2\lambda_0^3) \sim 10^{-2}(\xi/\lambda_0)^3$. Assuming $\lambda_0 = 150\,nm$, $\lambda_0/\xi = 10$ and $z_0 \sim 0.3\lambda_0$, for which $R_\rho,\ R_z \sim 1$ (Fig. 3a), gives $(<\ (\delta F)^2\ >)^{1/2} \sim 2\times 10^{-2}\epsilon_0(M_z/\phi_0\lambda_0)^2 \sim 2\times 10^{-1}(M_z/\phi_0\lambda_0)^2\ pN$, for both the lateral and perpendicular force components. Thus, the predicted value of $(<(\delta F)^2>)^{1/2}$ are larger than $1\,pN$ for $M_z/\phi_0\lambda_0 > 2$.

Localized Linear Defect. In this case $\delta m(\mathbf{r})$ is written as $\delta m(\mathbf{r}) = m_0\chi_m S_D(x)$, where $S_D(x) = [1 + (x/a_D)^{2n}]^{-1}$ is the defect shape function shown in Fig. 3b, χ_m a dimensionless constant, a_D the defect length scale, and n is a positive integer, chosen large in order that the boundary between the defect and the homogeneous superconductor is sharp. The assumption that $\delta m/m_0 \ll 1$ is equivalent $\mid \chi_m \mid \ll 1$. The force is given by

$$\delta\mathbf{F}(x_0, z_0) = 2\pi\epsilon_0(\frac{M_z}{\phi_0\lambda_0})^2\chi_m\mathbf{L}(x_0, z_0)\ , \quad (4)$$

where $\mathbf{L} = (L_x, L_z)$ is a dimensionless vector defined as:
$\mathbf{L} = \lambda_0^{-2}\boldsymbol{\nabla}_0\int d^2\rho\int_{-\infty}^0 dz a_0^2(\boldsymbol{\rho}, z; z_0)S_D(x+x_0, z)$. Typical results for L_x and L_z as functions of the dipole position coordinates, x_0 and z_0 are shown in Fig. 2c and Fig. 2d. The highlights of these figures are the following. The functions L_x and L_z are non-vanishing only in a range of $\mid x_0 \mid$ values comparable a_D, and decrease fast with increasing z_0. The former depends on the value chosen for a_D, and is true in general, except for $a_D \ll \lambda_0$. In this case the ranges of L_x and L_z are comparable to λ_0, because the range of $\mathbf{A}_0$ is λ_0, but their magnitudes are considerably reduced. The function L_x oscillates between positive and negative values, whereas L_z is always negative. This behavior results because L_x is related to the derivative of S_D and L_z to S_D itself, and from the functional dependence of S_D chosen here. For an order of magnitude estimate of the force, the same parameters used in the case of random point defects are adopted, and $\chi_m \sim 10^{-1}$ is chosen. The result is $\delta F_\alpha \sim 2\pi(M_z/\phi_0\lambda_0)^2\,L_\alpha\,pN$, where $\alpha = x,\ z$. The maximum values of the force components for $z_0 = 0.3\lambda_0$, using the results shown in Fig. 3, are $\delta F_x \sim 40(M_z/\phi_0\lambda_0)^2\,pN$, and $\delta F_z \sim 3\times 10^2(M_z/\phi_0\lambda_0)^2\,pN$. Thus, for $z_0 = 0.3\lambda_0$, force values $> 1\,pN$ are predicted for modest values of $M_z/\phi_0\lambda_0$.

The predictions for the force from linear defects is now compared to MFM force measurements at zero field reported in Ref.[4]. These measurements find that the perpendicular component of the force in the vicinity of a stacking fault dislocation in the superconducting material depends on the tip lateral position (see Fig.3 and Fig.4 of Ref.[4]) in a manner similar to that predicted here for a linear defect (Fig. 3d). The interpretation of these measurements based on the results of this paper is that the force behavior is

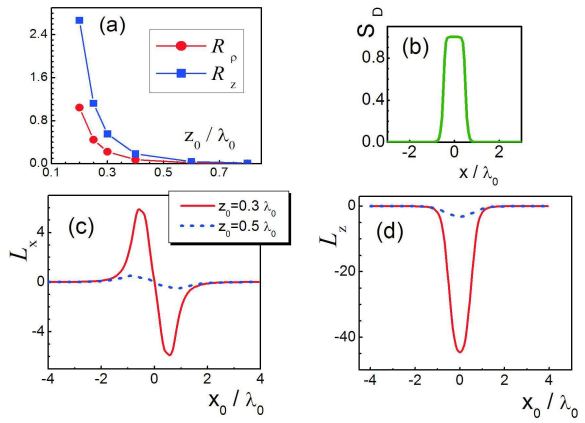

Figure 3. (a) Random defects functions $R_\rho(z_0)$ and $R_z(z_0)$ vs. z_0. (b) Linear defect shape function for $a_D = 0.5\lambda_0$, and $n = 5$ vs. dipole lateral position x_0. Linear defect functions L_x (c), and L_z (d) vs. x_0 and z_0.

due to the spatial dependence of mass parameter caused by the stacking fault dislocation. The latter statement is justified by the work reported in Ref.[5] showing that defects in the crystal lattice of the superconducting material cause spatial dependencies of the G-L parameters, and by the fact that the stacking fault dislocation in the sample used in Ref.[5] has an approximate linear symmetry. The authors of Ref.[4] interpret their results differently. They attribute the observed behavior to vortices created by unshielded magnetic fields, from the earth and from the experimental apparatus, pinned by the stacking fault dislocation. Both interpretations account qualitatively for the spatial dependence of the force. One possible way to distinguish between them experimentally would be to revert the tip magnetic moment and observe how the force changes. The contribution from defects to the force remains unchanged, whereas that from vortices changes sign.

In conclusion then this paper shows that defects in the superconducting material, as described by spatially dependent G-L mass parameters, give contributions to the force on the dipole with dependencies on the dipole lateral position characteristic of the type of defect. The order of magnitude estimates carried out here indicate that the force from random point defects is probably too small to be observed experimentally. On the other hand, the force from a linear localized defect is estimated to be larger than the resolution of the MFM technique, and may already been observed.

The calculations carried out here neglect creation of vortex matter by the dipole. This happens when the tip is close enough to the interface, because the dipole magnetic field inside the superconductor becomes large enough to create vortex half loops [3]. The presence of vortex matter changes the defect contribution to the force on the dipole. It is expected that, to first order in $\delta m/m_0$, it reduces the magnitude of this contribution. The reason is that the defect force results from the change in the kinetic energy caused by the inhomogeneity, and the vortex matter created by the dipole generates a current that opposes the dipole screening current, reducing the total current and, consequently, the kinetic energy. The question is how large this reduction is. To answer it requires considerations beyond the scope of this paper. Work along these lines in under way and will be reported elsewhere.

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